







IFN3954, IFN3955, IFN3956 Dual Matched N-Channel JFET

Features

- InterFET N0016H Geometry
- Typical Noise: 6 nV/VHz
- Low Ciss: 3.5pF Typical
- · High Input Impedance
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

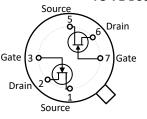
Applications

- · Differential Amplifiers
- · Low Noise Pre-Amplifier
- · High Impedance Amplifier

Description

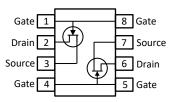
The -50V InterFET IFN3954, IFN3955, and IFN3956 matched pair JFET's are targeted for high input impedance applications for mid to high frequency designs. Gate leakages are typically 10pA at room temperatures. Parts are matched down to 5mV. The TO-71 package is hermetically sealed and suitable for military applications. Custom specifications, matching, and packaging options are available.

TO-71 Bottom View





SOIC8 Top View





Product Summary

	Parameters	IFN3954 Min	IFN3955 Min	IFN3956 Min	Unit
BV _{GSS}	Gate to Source Breakdown Voltage	-50	-50	-50	V
I _{DSS}	Drain to Source Saturation Current	0.5	0.5	0.5	mA
V _{GS(off)}	Gate to Source Cutoff Voltage	-1	-1	-1	V
G _{FS}	Forward Transconductance	1000	1000	1000	μS

Ordering Information Custom Part and Binning Options Available

Custom Fart and Billing Options Available						
Part Number	Description	Case	Packaging			
IFN3954; IFN3955; IFN3956	Through-Hole	TO-71	Bulk			
SMP3954; SMP3955; SMP3956	Surface Mount	SOIC8	Bulk			
SMP3954TR; SMP3955TR;	7" Tape and Reel: Max 500 Pieces		Minimum 500 Pieces			
SMP3956TR	13" Tape and Reel: Max 2,500 Pieces	SOIC8	Tape and Reel			
IFN3954COT; IFN3955COT;	Chip Orientated Tray					
IFN3956COT *	(COT Waffle Pack)	COT	70/Waffle Pack			
IFN3954CFT; IFN3955CFT;	Chip Face-up Tray					
IFN3956CFT *	(CFT Waffle Pack)	CFT	70/Waffle Pack			

^{*} Bare die packaged options are designed for matched specifications but not 100% tested



Disclaimer: It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.









Electrical Characteristics

Maximum Ratings (@ T_A = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
V_{RGS}	Reverse Gate Source and Gate Drain Voltage	-50	V
I _{FG}	Continuous Forward Gate Current	50	mA
PD	Continuous Device Power Dissipation	250	mW
Р	Power Derating	4.3	mW/°C
Tı	Operating Junction Temperature	-55 to 150	°C
T_{STG}	Storage Temperature	-65 to 175	°C

Static Characteristics (@ TA = 25°C, Unless otherwise specified)

			IFN3954, IFN3955, IFN3956			
	Parameters	Conditions	Min	Тур	Max	Unit
V _{(BR)GSS}	Gate to Source Breakdown Voltage	$I_G = -1\mu A$, $V_{DS} = 0V$	-50			V
I _{GSS}	Gate to Source Reverse Current	$V_{GS} = -30V$, $V_{DS} = 0V$, $T_A = 25$ °C $V_{GS} = -30V$, $V_{DS} = 0V$, $T_A = 125$ °C			-100 -500	pA nA
IG	Gate Operating Current	V _{DS} = 20V, I _D = 200μA, T _A = 25°C V _{DS} = 20V, I _D = 200μA, T _A = 125°C			-50 -250	pA nA
V _{GS(OFF)}	Gate to Source Cutoff Voltage	$V_{DS} = -20V$, $I_G = 1nA$	-1		-4.5	V
V _{GS}	Gate Source Voltage	$V_{DS} = 20V, I_D = 50\mu A$ $V_{DS} = 20V, I_D = 200\mu A$	-0.5		-4.2 -4	V
V _{GS(F)}	Gate Source Forward Voltage	$V_{DS} = 0V$, $I_G = 1mA$			2	V
I _{DSS}	Drain to Source Saturation Current	$V_{DS} = 20V$, $V_{GS} = 0V$ (Pulsed)	0.5		5	mA

Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

				IFN395	4, IFN3955, IF	N3956		
P	arameters	Conditions		Min	Тур	Max	Unit	
GFS	Forward	$V_{DS} = 10V, V_{GS} = 0V, f = 1kH$	lz	1000		3000	μS	
GF3	Transconductance	$V_{DS} = 20V, V_{GS} = 0V, f = 200N$	1Hz	1000			μο	
Gos	Output Conductance	$V_{DS} = 20V, f = 1kHz$				35	μS	
C _{iss}	Input Capacitance	$V_{DS} = 20V, V_{GS} = 0V, f = 1MH$	Ηz			4	pF	
C _{rss}	Reverse Capacitance	$V_{DS} = 20V, V_{GS} = 0V, f = 1MH$	Ηz			1.2	pF	
NF	Noise Figure	$V_{DS} = 20V, f = 10Hz, R_G = 10N$	ΛΩ			0.5	dB	
$ I_{G1} - I_{G2} $	Differential Gate Current	V _{DS} = 20V, I _D = 200μA, T _A = 12	.5°C			10	nA	
I _{DSS1} /I _{DSS2}	Saturation Drain Current Ratio	$V_{DS} = 20V, V_{GS} = 0V$		0.95		1		
V _{GS1} – V _{GS2}	Differential Gate Source Voltage	$V_{DS} = 20V, I_D = 200\mu A$ IFI	N3954 N3955 N3956			5 10 15	mV	
$\frac{\left V_{GS1}-V_{GS2}\right }{\Delta T}$	Differential Gate Source Voltage with Temperature	V _{DS} = 20V, I _D = 200μA T _O = -55°C to 125°C	N3954 N3955 N3956			1 2.5 5	mV/°C	
gfs1/gfs2	Transconductance Ratio	V _{DS} = 20V, I _D = 200μA, f = 1k	Hz	0.97		1		



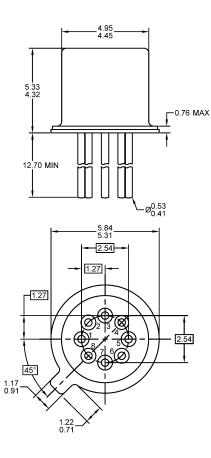






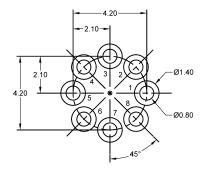
TO-71 Mechanical and Layout Data

Package Outline Data



- 1. All linear dimensions are in millimeters.
- Eight leaded device. Not all leads are shown in drawing views.
- 3. Some package configurations will not populate pin 8 and/or pin 4.
- 4. Package weight approximately 0.35 grams
- Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

Suggested Bent Lead Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- Pads 8 and/or pad 4 can be eliminated for devices with less pins.
- The suggested land pattern dimensions have been provided as an eight pin bent lead reference only. A more robust pattern may be desired for wave soldering or reduced pin count.



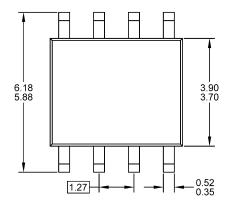


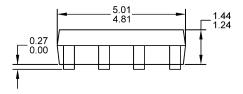


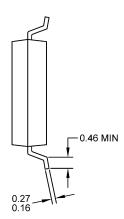


SOIC8 Mechanical and Layout Data

Package Outline Data

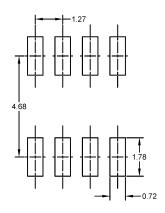






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.21 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

Suggested Pad Layout



- 1. All linear dimensions are in millimeters.
- The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.

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